



Rev.01 - 07 February 2022

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a TO220 plastic package intended for use in applications requiring good bidirectional blocking voltage and high surge current capability and high junction temperature capability ($T_{i(max)}$ = 150 °C).

2. Features and benefits

- High junction operating temperature capability (T_{j(max)} = 150 °C)
- · High bidirectional blocking voltage capability
- · Very high current surge capability
- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	1	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	-	600	V
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	half sine wave; T _{mb} ≤ 135 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	-	30	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	-	360	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	-	-	396	А
Tj	junction temperature		-	-	-	150	°C
Static ch	aracteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>		5	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	-	40	mA
V _T	on-state voltage	I _T = 30 A; T _j = 25 ° C ; <u>Fig. 10</u>		-	-	1.5	V
Dynamic	characteristics						
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 150 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM}); exponential waveform; gate open circuit$		500	-	-	V/µs

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	A	anode		А Д К G
3	G	gate		sym037
mb	A	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering	g information
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Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
TYN30-600TF	TO220	TYN30-600TFQ	Tube	50	SOT78	13-Jun-2008

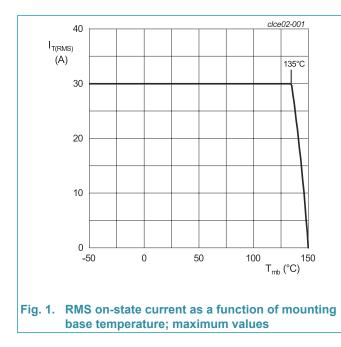
7. Marking

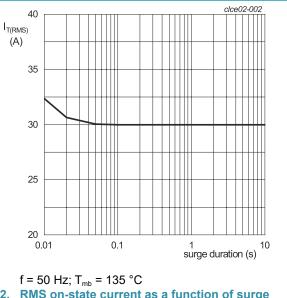
8. Limiting values

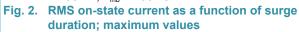
Table 5. Limiting values

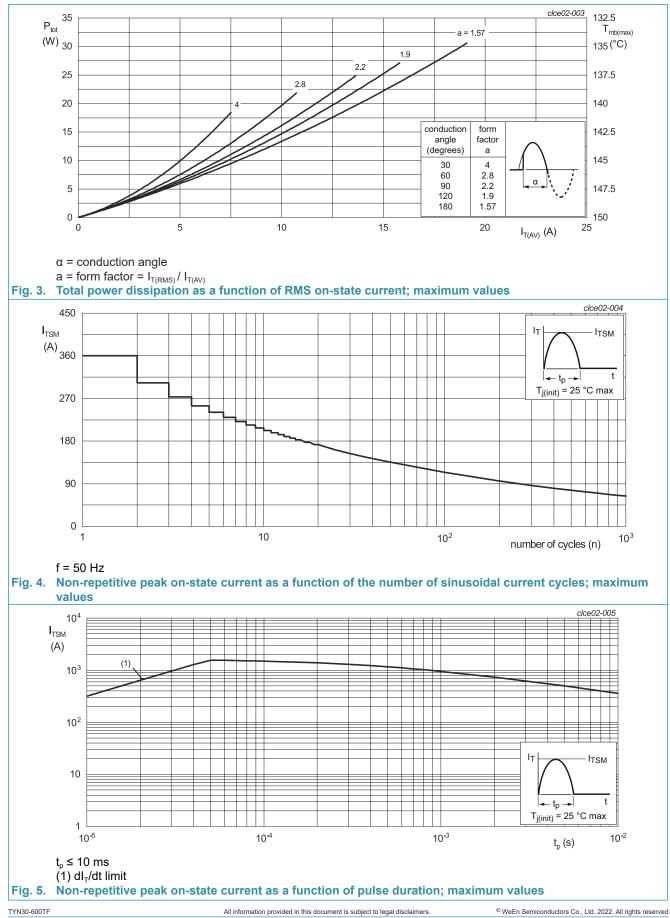
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{drm}	repetitive peak off-state voltage		-	600	V
V_{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; $T_{mb} \le 135 \text{ °C}$;	-	19	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 135 °C; Fig. 1; Fig. 2; Fig. <u>3</u>	-	30	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	360	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	396	А
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse	-	648	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 20 mA	-	150	A/µs
I _{GM}	peak gate current		-	5	А
V _{GM}	peak gate voltage		-	5	V
P _{GM}	peak gate power		-	20	W
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	150	°C



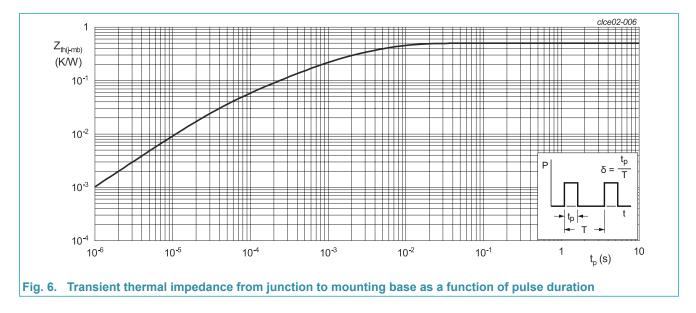






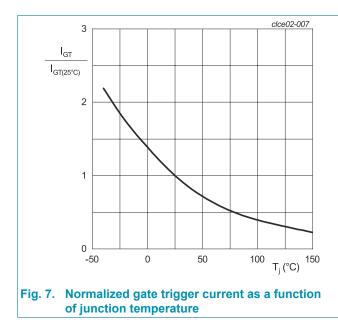
9. Thermal characteristics

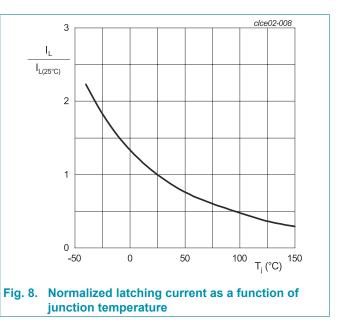
Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	0.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W

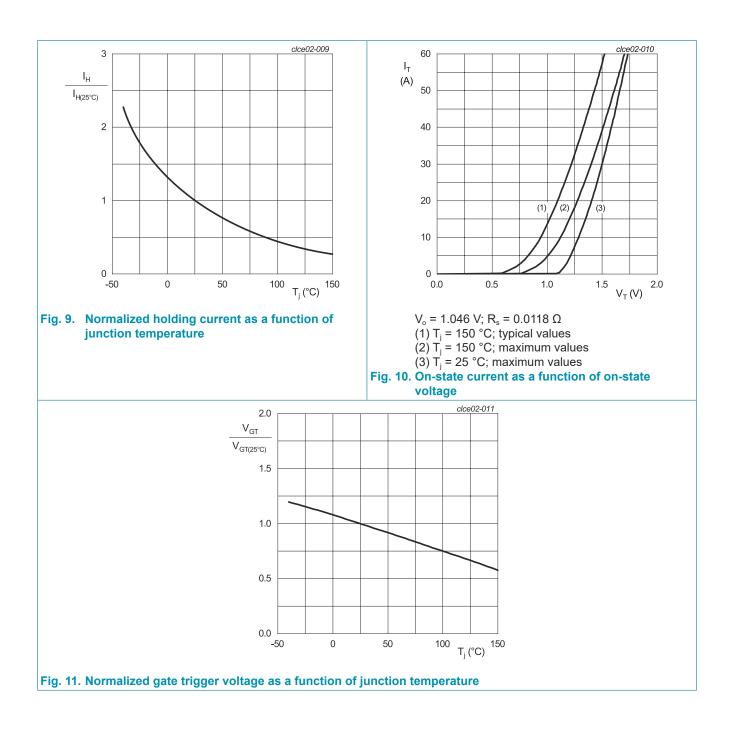


10. Characteristics

able 7. Cl	haracteristics					_
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	V_{D} = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	5	-	10	mA
I _L	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	-	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	I _T = 30 A; T _j = 25 °C; <u>Fig. 10</u>	-	-	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	-	0.8	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.25	0.45	-	V
V _{gr}	gate reverse voltage	I _{RG} = 100 mA	10	-	-	V
I _D	off-state current	V _D = 600 V; T _j = 25 °C	-	-	10	μA
		V _D = 600 V; T _j = 150 °C	-	-	2	mA
I _R	reverse current	V _D = 600 V; T _j = 25 °C	-	-	10	μA
		V _D = 600 V; T _j = 150 °C	-	-	2	mA
Dynamic	characteristics	· · · · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 30 \text{ A}; V_D = 600 \text{ V}; I_G = 20 \text{ mA};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C}$	-	2	-	μs
t _q	commutated turn-off time	I_{TM} = 2 A; t _p = 50 µs; dV/dt = 5 V/µs; dI/dt = 30 A/µs	-	-	12	μs

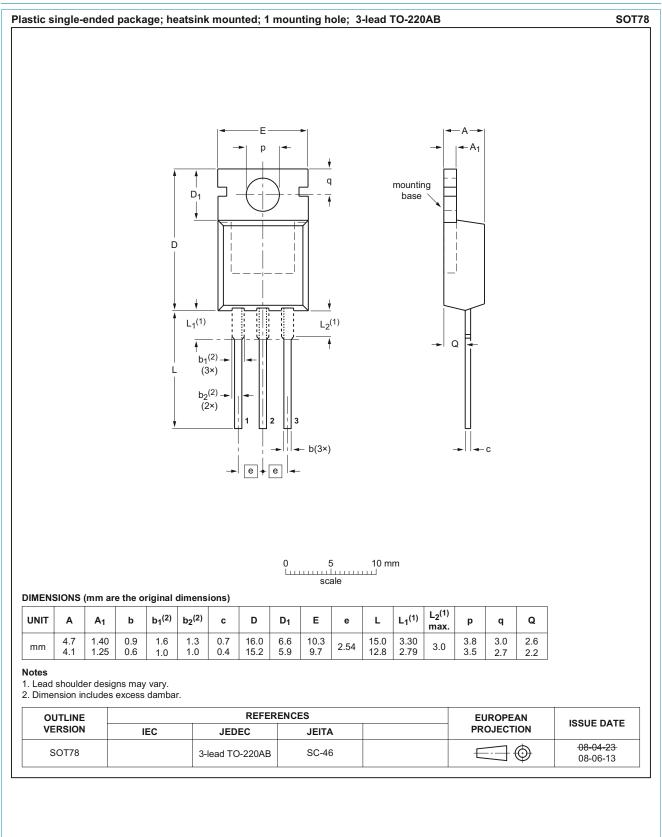








11. Package outline



TYN30-600TF Product data sheet

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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